NSN 5961-00-919-6816

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View Online at https://aerobasegroup.com/nsn/5961-00-919-6816 **Inclosure Material:** Metal **Overall Length:** 0.406 inches **Overall Diameter:** 0.828 inches **End Application:** Guided missile, intercept **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.865 inches **Thread Size:** 0.312 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 breakdown voltage, collector-to-base, emitter open and 90.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Weapon system essential; junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release4639 professional/industrial association specification Shelf Life:

N/a

Unit Of Measure:

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